

View Online at <https://aerobasegroup.com/nsn/5961-01-349-9021>

Inclosure Material:

Metal

Overall Length:

Between 0.026 inches and 0.028 inches

Function For Which Designed:

Microwave

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Terminal

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

0.4 forward voltage, dc all semiconductor device diode

Power Rating Per Characteristic:

75.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

Capacitance Rating In Picofarads:

0.1 all semiconductor device diode and 0.3 all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

All semiconductor device diode junction pattern arrangement: pn

Terminal Type And Quantity:

2 beam lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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